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<u>Fairchild Semiconductor</u> <u>BD534J</u>

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BD534/536/538

Medium Power Linear and Switching Applications

- Low Saturation Voltage
- Complement to BD533, BD535 and BD537 respectively



1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Para	Value	Units	
V _{CBO}	Collector-Base Voltage	: BD534	- 45	V
		: BD536	- 60	V
		: BD538	- 80	V
V _{CEO}	Collector-Emitter Voltage	: BD534	- 45	V
		: BD536	- 60	V
		: BD538	- 80	V
V _{EBO}	Emitter-Base Voltage		- 5	V
I _C	Collector Current (DC)		- 8	Α
I _B	Base Current	- 1	Α	
P _C	Collector Dissipation (T _C =25°C	50	W	
T _J	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 65 ~ 150	°C	

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Para	meter		Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off C	urrent	: BD534	$V_{CB} = -45V, I_{E} = 0$			- 100	μΑ
			: BD536	$V_{CB} = -60V, I_{E} = 0$			- 100	μΑ
			: BD538	$V_{CB} = -80V, I_{E} = 0$			- 100	μΑ
I _{CES}	Collector Cut-off C	urrent	: BD534	$V_{CE} = -45V, V_{BE} = 0$			- 100	μΑ
			: BD536	$V_{CE} = -60V, V_{BE} = 0$			- 100	μΑ
			: BD538	$V_{CE} = -80V, V_{BE} = 0$			- 100	μΑ
I _{EBO}	Emitter Cut-off Cu	rrent		$V_{EB} = -5V, I_{C} = 0$			- 1	mA
h _{FE}	* DC Current Gain	: ALI	_ DEVICE	$V_{CE} = -2 \text{ V, } I_{C} = -500 \text{mA}$	40			
		: BD53	34/536	$V_{CE} = -5V, I_{C} = -10mA$	20			
		: BD53	38		15			
		: BD53	34/536	$V_{CE} = -2V, I_{C} = -2A$	25			
		: BD53	38		15			
h _{FE}	h _{FE} Groups							
	J	: ALL	DEVICE	$V_{CE} = -2V, I_{C} = -2A$	30		75	
				$V_{CE} = -2V, I_{C} = -3A$	15			
	K	: ALL	DEVICE	$V_{CE} = -2V, I_{C} = -2A$	40		100	
				$V_{CE} = -2V, I_{C} = -3A$	20			
V _{CE} (sat)	V _{CE} (sat) * Collector-Emitter Saturation Voltage		$I_C = -2A, I_B = -0.2A$			- 0.8	V	
				$I_C = -6A, I_B = -0.6A$		- 0.8		V
V _{BE} (on)	* Base-Emitter ON Voltage			$V_{CE} = -2V, I_{C} = -2A$			- 1.5	V
f _T	Current Gain Bandwidth Product		$V_{CE} = -1V, I_{C} = -500 \text{mA}$	3	12		MHz	
Pulse Test: PV	Pulse Test: PW =300µs, duty Cycle =1.5% Pulsed							

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Typical Characteristics

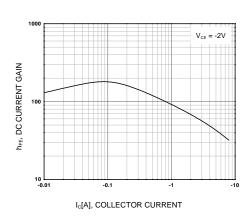


Figure 1. DC current Gain

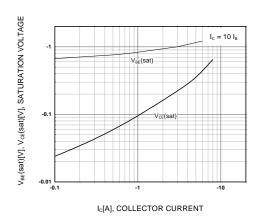


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

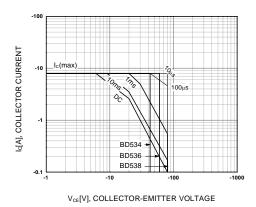


Figure 3. Safe Operating Area

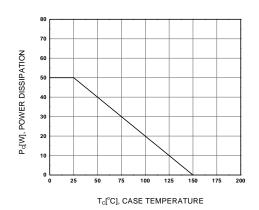


Figure 4. Power Derating

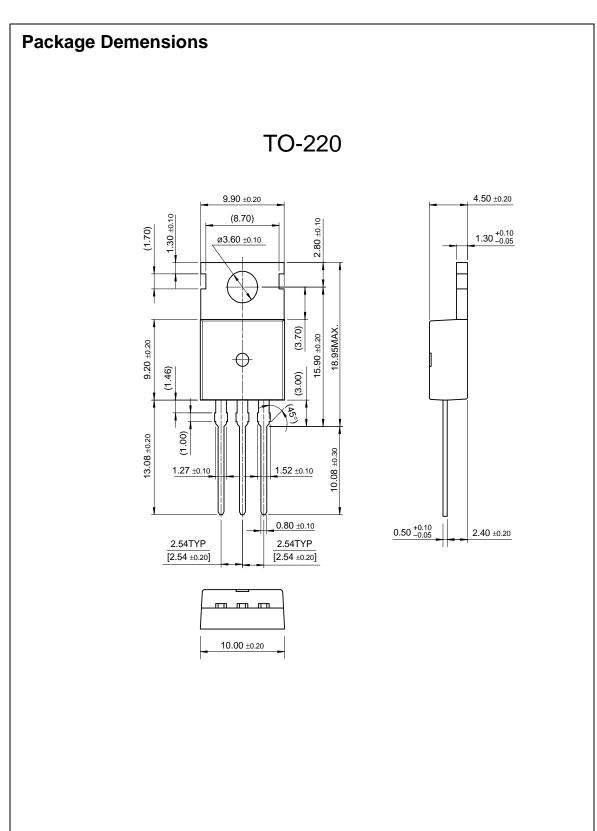
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Dimensions in Millimeters

Rev. A, February 2000



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Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of BD534J - TRANS PNP 45V 8A TO-220

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